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Kind regards,

Team Nexperia

# 1PS79SB10

# Schottky barrier single diode

14 August 2012

**Product data sheet** 

# 1. Product profile

#### 1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Low forward voltage
- Guard ring protected
- Ultra small plastic SMD package
- AEC-Q101 qualified

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Blocking diodes

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current		-	-	200	mA
V <sub>R</sub>	reverse voltage		-	-	30	٧
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	-	400	mV

## 2. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	1 2	к <b>-</b> Д∕-А
2	Α	anode	SOD523	aaa-003679

<sup>[1]</sup> The marking bar indicates the cathode.





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# 3. Ordering information

#### Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
1PS79SB10	SOD523	plastic surface-mounted package; 2 leads	SOD523			

# 4. Marking

#### Table 4. Marking codes

Type number	Marking code
1PS79SB10	F

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
T <sub>j</sub>	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-65	125	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

### 6. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	450	K/W

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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### 7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 mA; T <sub>amb</sub> = 25 °C	-	-	240	mV
		I <sub>F</sub> = 1 mA; T <sub>amb</sub> = 25 °C	-	-	320	mV
		I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	-	400	mV
		I <sub>F</sub> = 30 mA; T <sub>amb</sub> = 25 °C	-	-	500	mV
		I <sub>F</sub> = 100 mA; T <sub>amb</sub> = 25 °C	-	-	800	mV
I <sub>R</sub>	reverse current	$V_R = 25 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed};$ $t_p = 300  \mu\text{s}; \delta = 0.02$	-	-	2	μA
C <sub>d</sub>	diode capacitance	f = 1 MHz; T <sub>amb</sub> = 25 °C; V <sub>R</sub> = 1 V	-	-	10	pF

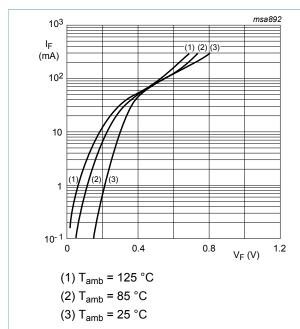
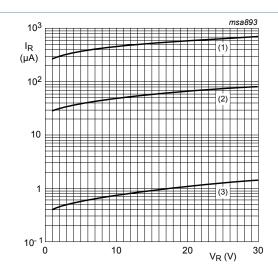


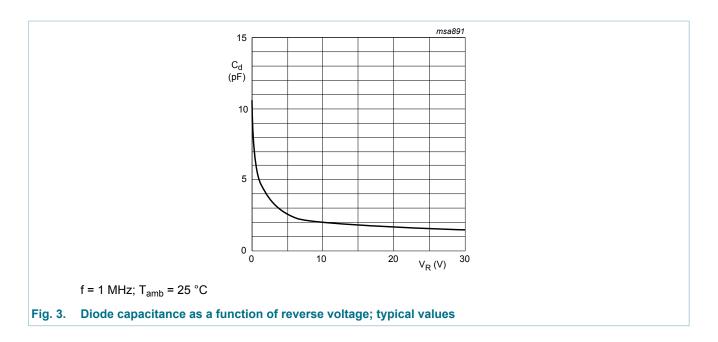
Fig. 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig. 2. Reverse current as a function of reverse voltage; typical values

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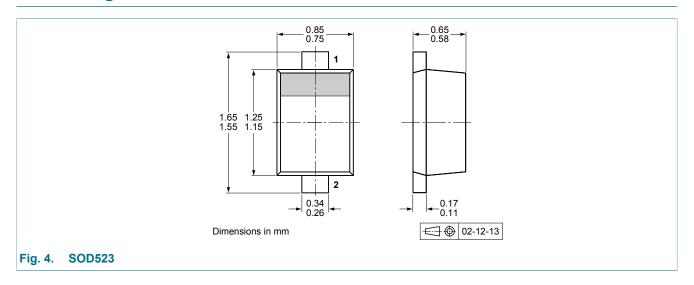


### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

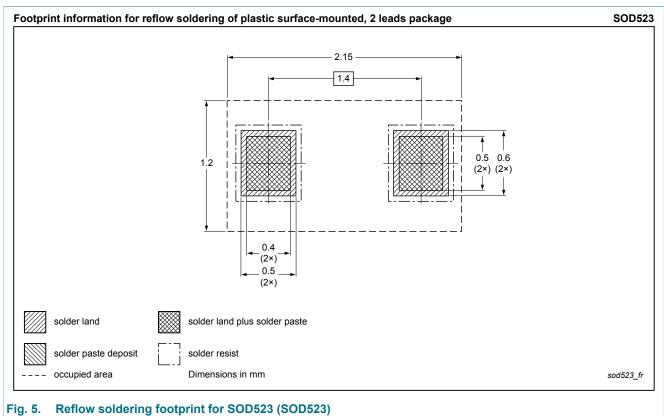
### 9. Package outline



**Product data sheet** 

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### 10. Soldering



# 11. Revision history

Table 8. **Revision history** 

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS79SB10 v.2	20120814	Product data sheet	-	1PS79SB10 v.1
Modifications:	of NXP Semicond • Legal texts have b	peen adapted to the new corawing replaced by minimi mation" added.	ompany name where app	ropriate.
1PS79SB10 v.1	19980716	Product data sheet	-	-

#### Schottky barrier single diode

### 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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1PS79SB10

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